

# SKKT 80/16 E



## Thyristor Modules

### SKKT 80/16 E

#### Features\*

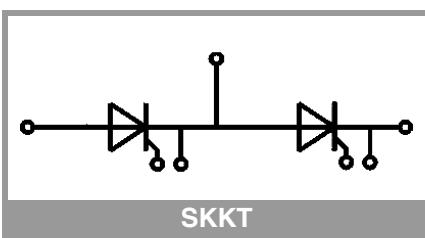
- Heat transfer through aluminium oxide ceramic insulated metal baseplate
- UL recognized, file no. E63532

#### Typical Applications

- DC motor control (e. g. for machine tools)
- AC motor soft starters
- Temperature control (e. g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

Absolute Maximum Ratings		Values		Unit
Symbol	Conditions			
<b>Chip</b>				
$I_{T(AV)}$	$\sin. 180^\circ$ $T_j = 130^\circ\text{C}$	$T_c = 85^\circ\text{C}$ $T_c = 100^\circ\text{C}$	81 62	A
$I_{TSM}$	$t_p = 10 \text{ ms}$	$T_j = 25^\circ\text{C}$ $T_j = 130^\circ\text{C}$	1500 1200	A
$i^2t$	$t_p = 10 \text{ ms}$	$T_j = 25^\circ\text{C}$ $T_j = 130^\circ\text{C}$	11250 7200	$\text{A}^2\text{s}$
$V_{RSM}$	$T_j = 25^\circ\text{C}$		1700	V
$V_{RRM}$	$T_j = 25^\circ\text{C}$		1600	V
$V_{DRM}$	$T_j = 25^\circ\text{C}$		1600	V
$(di/dt)_{cr}$	$T_j = 130^\circ\text{C}$		200	$\text{A}/\mu\text{s}$
$(dv/dt)_{cr}$	$T_j = 130^\circ\text{C}$		1000	$\text{V}/\mu\text{s}$
$T_j$			-40 ... 130	$^\circ\text{C}$
<b>Module</b>				
$T_{stg}$			-40 ... 125	$^\circ\text{C}$
$V_{isol}$	a.c.; 50 Hz; r.m.s.	1 min 1 s	3000 3600	V

Characteristics		min.	typ.	max.	Unit
Symbol	Conditions				
<b>Chip</b>					
$V_T$	$T_j = 25^\circ\text{C}$ , $I_T = 240 \text{ A}$			1.85	V
$V_{T(TO)}$	$T_j = 130^\circ\text{C}$			0.92	V
$r_T$	$T_j = 130^\circ\text{C}$			4.6	$\text{m}\Omega$
$I_{DD}, I_{RD}$	$T_j = 130^\circ\text{C}$ , $V_{DD} = V_{DRM}$ ; $V_{RD} = V_{RRM}$			15	mA
$t_{gd}$	$T_j = 25^\circ\text{C}$ , $I_G = 1 \text{ A}$ , $dI_G/dt = 1 \text{ A}/\mu\text{s}$		1		$\mu\text{s}$
$t_{gr}$	$V_D = 0.67 * V_{DRM}$		2		$\mu\text{s}$
$t_q$	$T_j = 130^\circ\text{C}$		200		$\mu\text{s}$
$I_H$	$T_j = 25^\circ\text{C}$			220	mA
$I_L$	$T_j = 25^\circ\text{C}$ , $R_G = 33 \Omega$			550	mA
$V_{GT}$	$T_j = 25^\circ\text{C}$ , d.c.		2.5		V
$I_{GT}$	$T_j = 25^\circ\text{C}$ , d.c.		100		mA
$V_{GD}$	$T_j = 130^\circ\text{C}$ , d.c.			0.25	V
$I_{GD}$	$T_j = 130^\circ\text{C}$ , d.c.			4	mA
$R_{th(j-c)}$	continuous DC	per chip per module		0.23 0.115	K/W
$R_{th(j-c)}$	sin. $180^\circ$	per chip per module		0.30 0.15	K/W
$R_{th(j-c)}$	rec. $120^\circ$	per chip per module		0.32 0.16	K/W
<b>Module</b>					
$R_{th(c-s)}$	per chip ( $\lambda_{grease} = 0.81 \text{ W}/(\text{m}^*\text{K})$ ) per module ( $\lambda_{grease} = 0.81 \text{ W}/(\text{m}^*\text{K})$ )		0.09 0.05		K/W
$M_s$	to heatsink M5		4.25	5.75	Nm
$M_t$	to terminals M5		2.55	3.45	Nm
$a$				5 * 9.81	$\text{m}/\text{s}^2$
$w$			75		g



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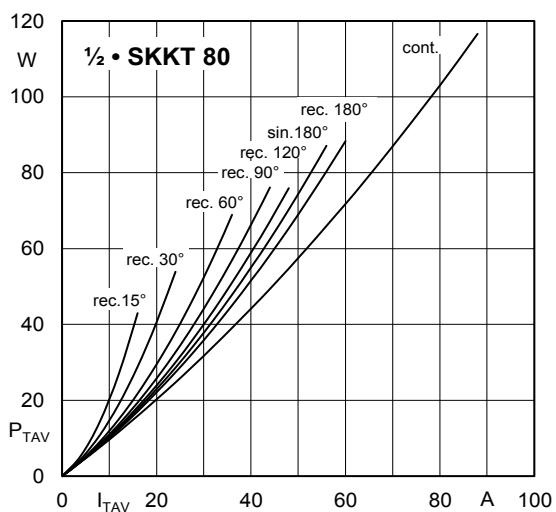


Fig. 1L: Power dissipation per thyristor vs. on-state current

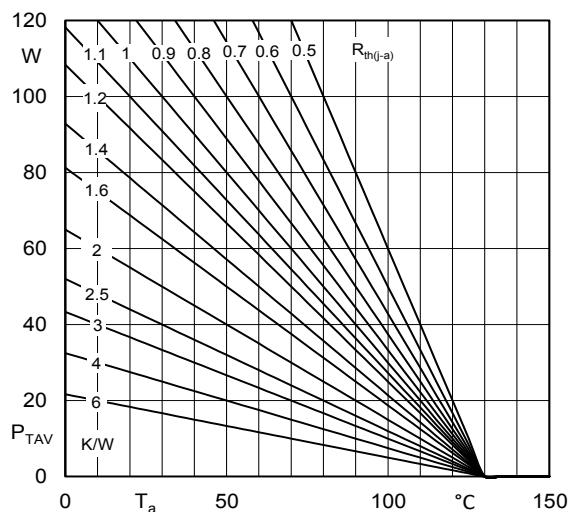


Fig. 1R: Max. power dissipation per chip vs. ambient temperature

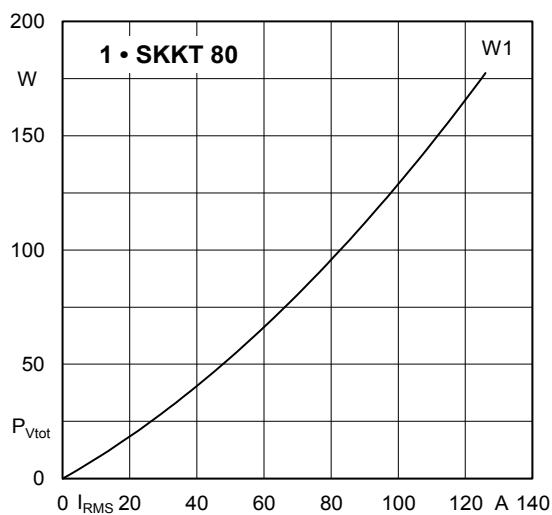


Fig. 2L: Max. power dissipation of one module vs. rms current

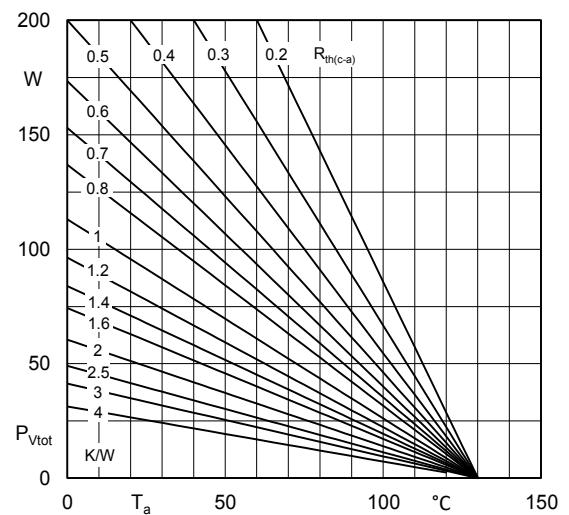


Fig. 2R: Max. power dissipation of one module vs. ambient temperature

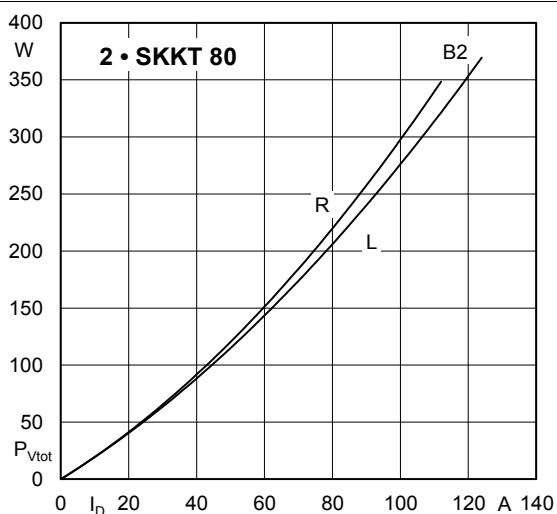


Fig. 3L: Max. power dissipation of two modules vs. direct current

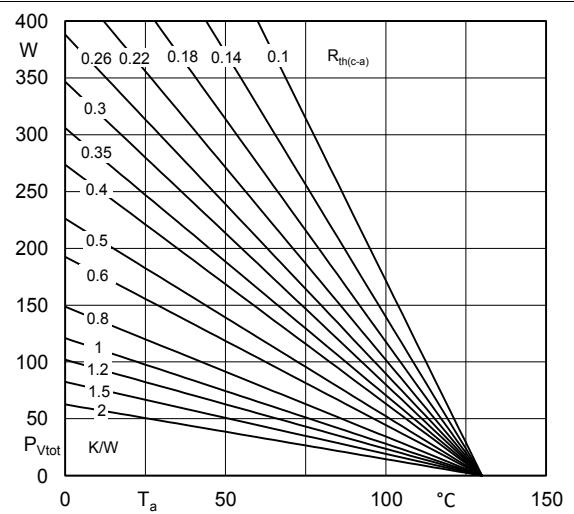


Fig. 3R: Max. power dissipation of two modules vs. ambient temperature

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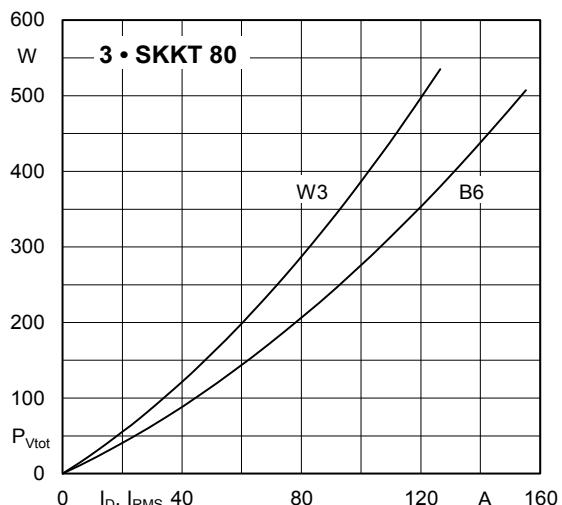


Fig. 4L: Max. power dissipation of three modules vs. direct current

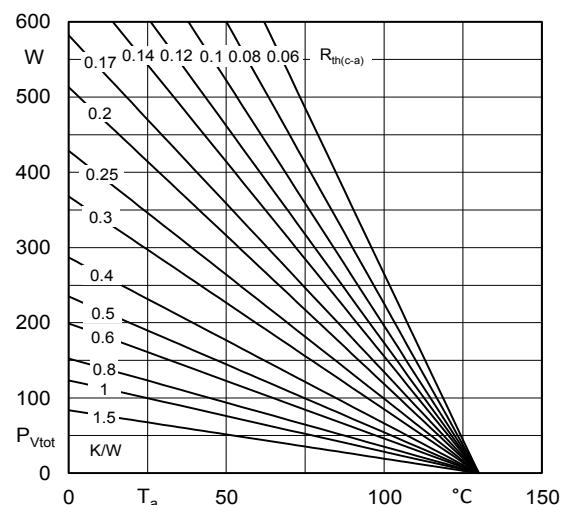


Fig. 4R: Max. power dissipation of three modules vs. ambient temperature

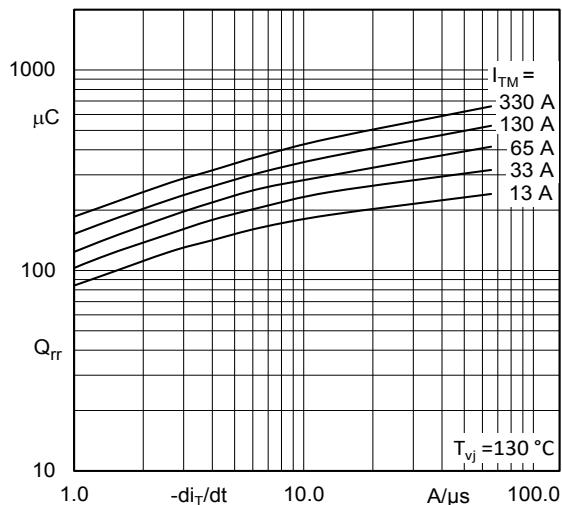


Fig. 5: Recovered charge vs. current decrease

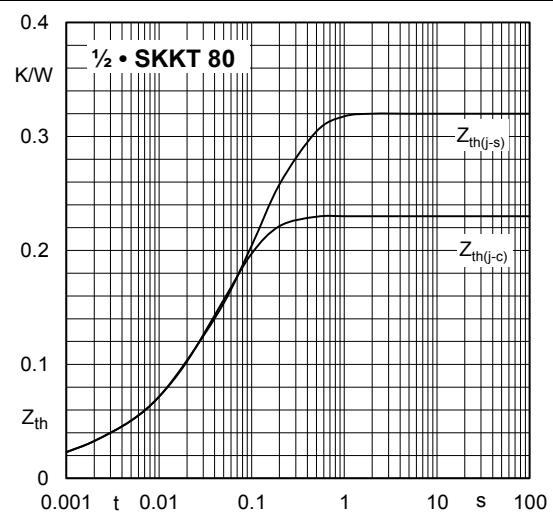


Fig. 6: Transient thermal impedance vs. time

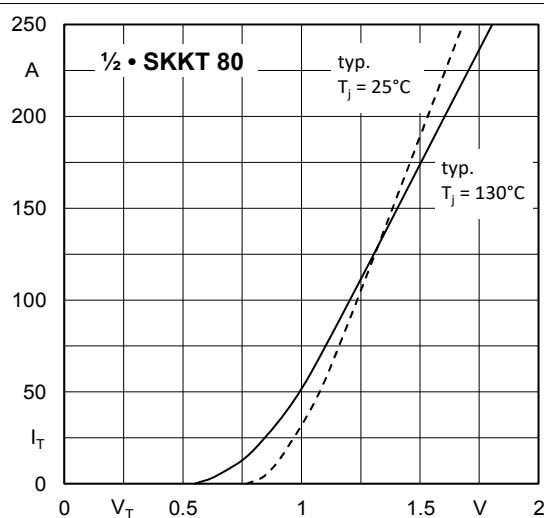


Fig. 7: On-state characteristics

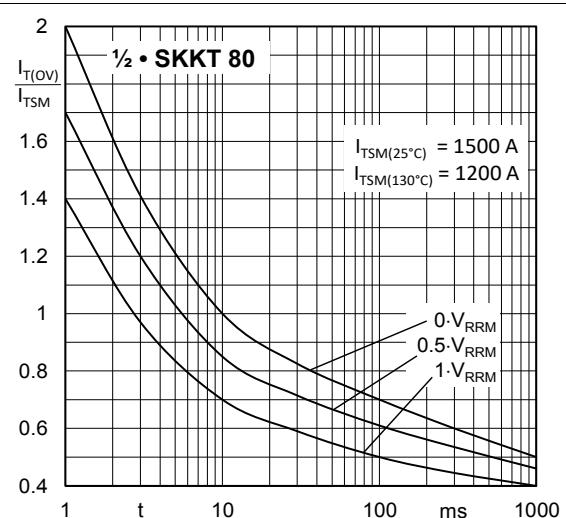


Fig. 8: Surge overload current vs. time

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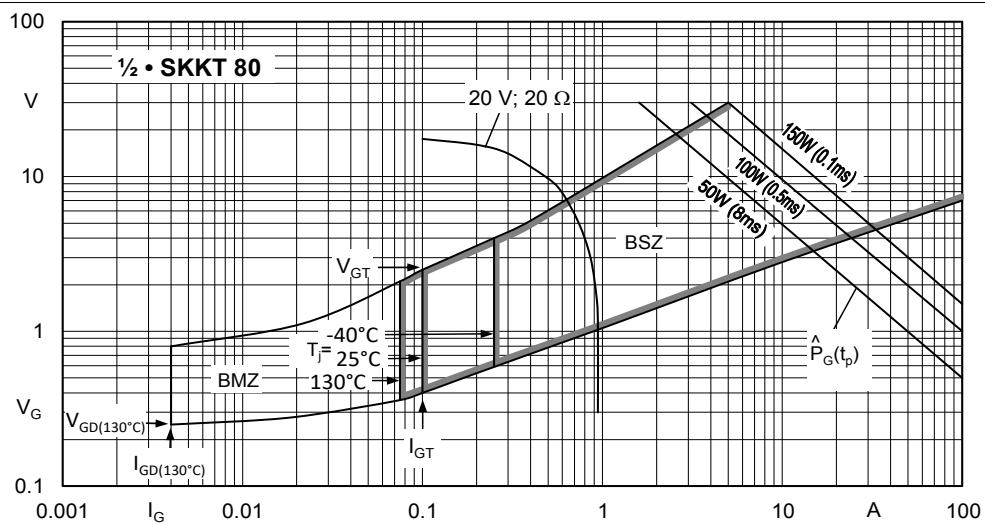
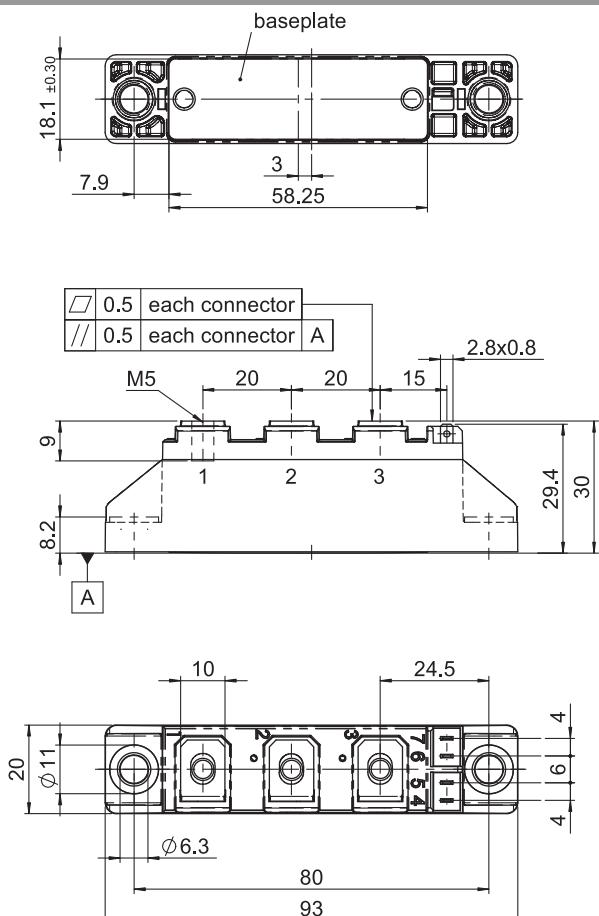
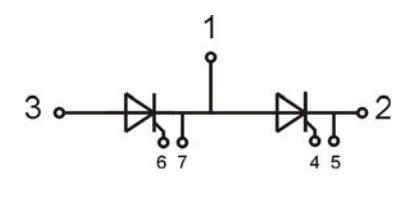


Fig. 9: Gate trigger characteristics



SEMIPACK 1



## IMPORTANT INFORMATION AND WARNINGS

This is an electrostatic discharge sensitive device (ESDS) according to international standard IEC 61340.

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